

Atty. Docket No. 8013-1036

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Naoki FURUHATA

A.

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ROUP 2823
Examiner W. Coleman FCHNOLOGY CENTER 2800

Serial No. 09/848,263

Filed May 4, 2001

MONOLITHIC COMPOUND SEMICONDUCTOR INTEGRATED CIRCUIT AND METHOD OF FORMING THE SAME

AMENDMENT

Commissioner for Patents

Washington, D.C. 20231

Sir:

Responsive to the Official Action of June 14, 2002, please amend the above-identified application as follows:

ABSTRACT OF THE DISCLOSURE:

Rewrite the Abstract of the Disclosure as on the accompanying separate sheet.

IN THE SPECIFICATION:

Page 2, replace the paragraph beginning on line 5 as follows:

--Japanese laid-open patent publication No. 10-107042 discloses a conventional monolithic microwave integrated circuit. Such a conventional integrated circuit has the following The hetero-junction bipolar transistor and the metal problems. insulator metal capacitor are separately formed using separate